

Nanopower Precision Shunt Voltage Reference

FEATURES

- **Initial Voltage Accuracy: 0.05%**
- **Low Operating Current: 800nA**
- **Low Drift: 10ppm/°C Max**
- Less Than 1Ω Dynamic Impedance
- Available in 1.25V, 2.5V, 4.096V and 5V SO-8 Packages

APPLICATIONS

- Portable Meters
- Precision Regulators
- A/D and D/A Converters
- Calibrators

DESCRIPTION

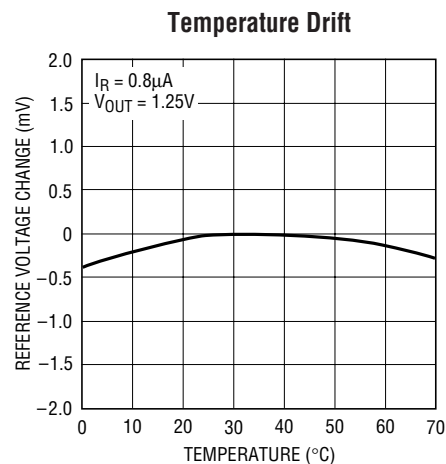
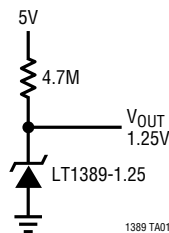
The LT[®]1389 is a nanopower, precision shunt voltage reference. The bandgap reference uses trimmed precision thin-film resistors and improved curvature correction techniques to achieve 0.05% initial voltage accuracy with guaranteed 10ppm/°C maximum temperature drift. Voltage regulation is maintained to an ultralow 800nA operating current. Advances in design, processing and packaging achieve low temperature cycling hysteresis.

The LT1389 does not require an output compensation capacitor, but is stable with capacitive loads. Low dynamic impedance makes the LT1389 reference easy to use from unregulated supplies.

The LT1389 reference can be used as a high performance upgrade to the LM185/LM385, LT1004, LT1034 and LT1634 where lowest power and guaranteed temperature drift are required.

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TYPICAL APPLICATION



ABSOLUTE MAXIMUM RATINGS

(Note 1)

Operating Current

1.25V 20mA

2.5V 20mA

4.096V 10mA

5V 10mA

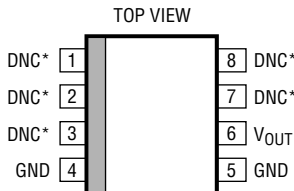
Forward Current 20mA

Operating Temperature Range 0°C to 70°C

Storage Temperature Range (Note 2) ... -65°C to 150°C

Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION

	ORDER PART NUMBER	
	S8 PART MARKING	
	LT1389ACS8-1.25	389A12
	LT1389BCS8-1.25	389B12
	LT1389BCS8-2.5	389B25
	LT1389BCS8-4.096	1389B4
	LT1389BCS8-5	1389B5

*Connected internally. Do Not Connect external circuitry to these pins.
Consult factory for Industrial and Military grade parts.

AVAILABLE OPTIONS

TEMPERATURE	OUTPUT VOLTAGE	ACCURACY (%)	TEMPERATURE COEFFICIENT (ppm/°C)	PART TYPE	PART MARKING
0°C to 70°C	1.250	0.05	10	LT1389ACS8-1.25	389A12
	1.250	0.05	20	LT1389BCS8-1.25	389B12
	2.500	0.05	20	LT1389BCS8-2.5	389B25
	4.096	0.075	50	LT1389BCS8-4.096	1389B4
	5.000	0.075	50	LT1389BCS8-5	1389B5

1.25V ELECTRICAL CHARACTERISTICS The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389ACS8/LT1389BCS8 ($I_R = 0.8\mu\text{A}$)	1.24937 -0.05	1.250	1.25062 0.05	V %
	LT1389ACS8 ($I_R = 0.8\mu\text{A}$) ●	1.24849 -0.12	1.250	1.25149 0.12	V %
	LT1389BCS8 ($I_R = 0.8\mu\text{A}$) ●	1.24762 -0.19	1.250	1.25237 0.19	V %
Reverse Breakdown Change with Current (Note 4)	$0.8\mu\text{A} \leq I_R \leq 200\mu\text{A}$ ●		0.20 0.20	0.4 1.0	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$ ●		0.3 0.3	1.0 2.0	mV mV
Minimum Operating Current	●			0.6	μA
Temperature Coefficient	LT1389ACS8 ($I_R = 0.8\mu\text{A}$) ●		4	10	ppm/°C
	LT1389BCS8 ($I_R = 0.8\mu\text{A}$) ●		4	20	ppm/°C
Reverse Dynamic Impedance (Note 5)	$0.8\mu\text{A} \leq I_R \leq 2\text{mA}$ ●		0.25	0.7	Ω
			0.25	1.5	Ω
Low Frequency Noise (Note 6)	$I_R = 0.8\mu\text{A}$, $0.1\text{Hz} \leq f \leq 10\text{Hz}$		25		μV_{P-P}

2.5V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 ($I_R = 0.9\mu\text{A}$)		2.49875 −0.05	2.500	2.50125 0.05	V %
	LT1389BCS8 ($I_R = 0.9\mu\text{A}$)	●	2.49525 −0.19	2.500	2.50475 0.19	V %
Reverse Breakdown Change with Current (Note 4)	$0.9\mu\text{A} \leq I_R \leq 200\mu\text{A}$	●		0.2 0.2	0.5 1.5	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$	●		0.3 0.3	1.0 2.5	mV mV
		●			0.7	μA
Minimum Operating Current		●			0.7	μA
Temperature Coefficient	$I_R = 0.9\mu\text{A}$	●		8	20	ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$0.9\mu\text{A} \leq I_R \leq 2\text{mA}$			0.25 0.25	0.75 2	Ω Ω
		●				
Low Frequency Noise (Note 6)	$I_R = 0.9\mu\text{A}$, $0.1\text{Hz} \leq f \leq 10\text{Hz}$			50		$\mu\text{V}_{\text{P-P}}$

4.096V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 ($I_R = 1.5\mu\text{A}$)		4.09293 −0.075	4.096	4.09907 0.075	V %
	LT1389BCS8 ($I_R = 1.5\mu\text{A}$)	●	4.0788 −0.42	4.096	4.1132 0.42	V %
Reverse Breakdown Change with Current (Note 4)	$1.5\mu\text{A} \leq I_R \leq 200\mu\text{A}$	●		0.2 0.2	1.5 3	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$	●		0.3 0.3	4 6	mV mV
		●			1	μA
Minimum Operating Current		●			1	μA
Temperature Coefficient	$I_R = 1.5\mu\text{A}$	●		12	50	ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$1.5\mu\text{A} \leq I_R \leq 2\text{mA}$			0.75 0.75	2 3	Ω Ω
		●				
Low Frequency Noise (Note 6)	$I_R = 1.5\mu\text{A}$, $0.1\text{Hz} \leq f \leq 10\text{Hz}$			80		$\mu\text{V}_{\text{P-P}}$

5V ELECTRICAL CHARACTERISTICS

The ● denotes specifications which apply over the full operating temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. (Note 3)

PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Reverse Breakdown Voltage	LT1389BCS8 ($I_R = 1.5\mu\text{A}$)		4.99625 –0.075	5.000	5.00375 0.075	V %
	LT1389BCS8 ($I_R = 1.5\mu\text{A}$)	●	4.979 –0.42	5.000	5.021 0.42	V %
Reverse Breakdown Change with Current (Note 4)	$1.5\mu\text{A} \leq I_R \leq 200\mu\text{A}$	●		0.2 0.2	1.5 3	mV mV
	$200\mu\text{A} \leq I_R \leq 2\text{mA}$	●		0.3 0.3	4 6	mV mV
Minimum Operating Current		●			1	μA
Temperature Coefficient	$I_R = 1.5\mu\text{A}$	●		12	50	ppm/ $^\circ\text{C}$
Reverse Dynamic Impedance (Note 5)	$1.5\mu\text{A} \leq I_R \leq 2\text{mA}$			0.75	2	Ω
		●		0.75	3	Ω
Low Frequency Noise (Note 6)	$I_R = 1.5\mu\text{A}$, $0.1\text{Hz} \leq f \leq 10\text{Hz}$			100		$\mu\text{V}_{\text{P-P}}$

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: If the part is stored outside of the specific operating temperature range, the output may shift due to hysteresis.

Note 3: ESD (Electrostatic Discharge) sensitive device. Use proper ESD handling precautions.

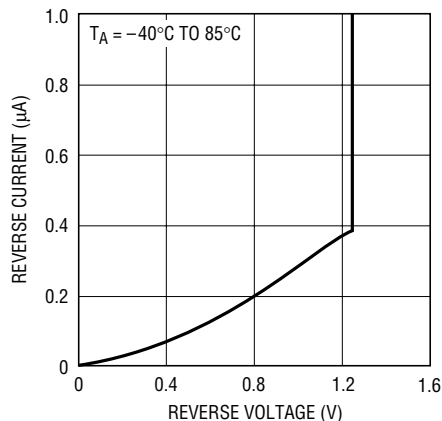
Note 4: Output requires $0.1\mu\text{F}$ for operating current greater than 1mA .

Note 5: This parameter is guaranteed by “reverse breakdown change with current” test.

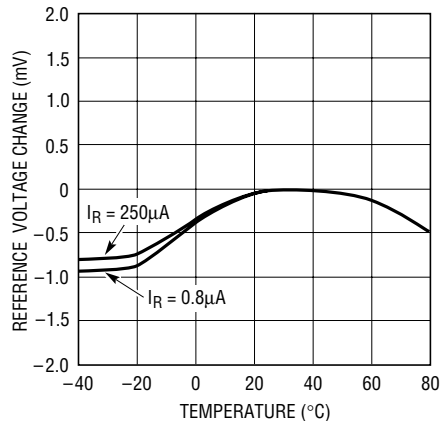
Note 6: Peak-to-peak noise is measured with a single highpass filter at 0.1Hz and 2-pole lowpass filter at 10Hz .

1.25V TYPICAL PERFORMANCE CHARACTERISTICS

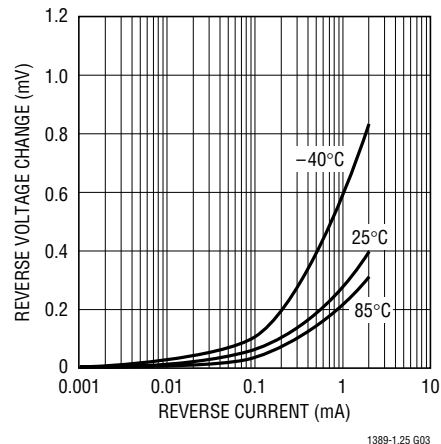
Reverse Characteristics



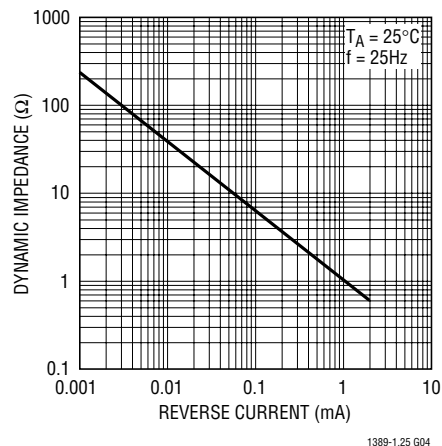
Temperature Drift



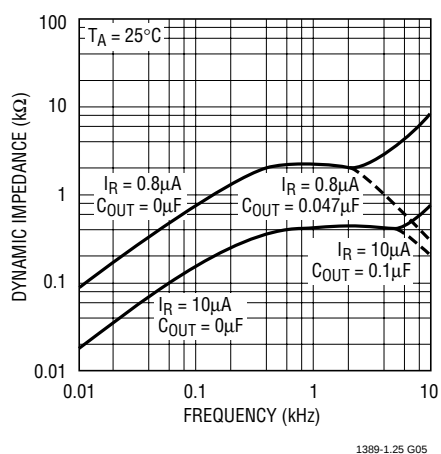
Reverse Voltage Change vs Current



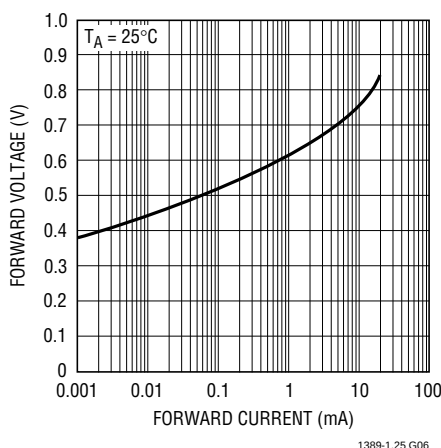
Reverse Dynamic Impedance



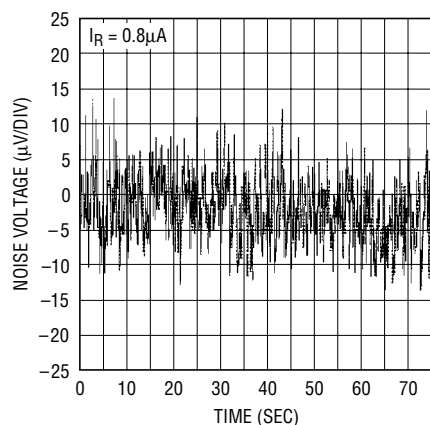
Dynamic Impedance vs Frequency



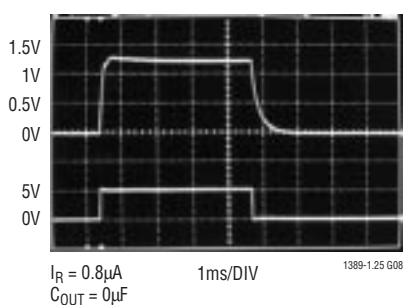
Forward Characteristics



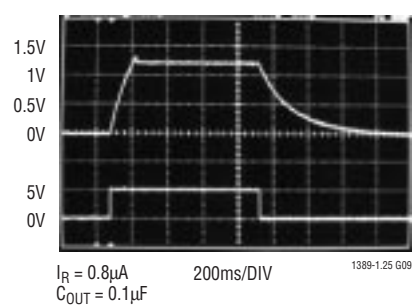
0.1Hz to 10Hz Noise



Response Time

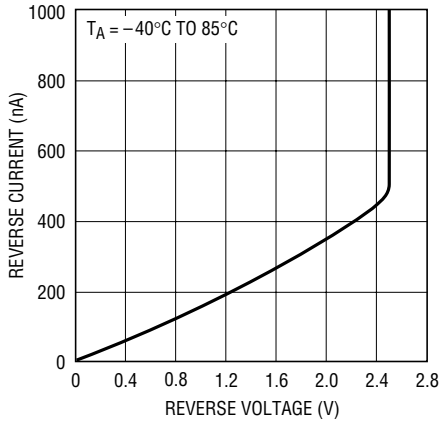


Response Time

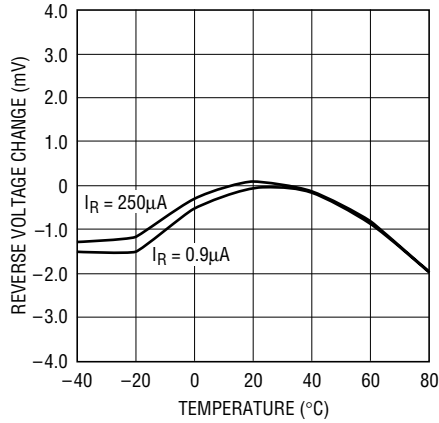


2.5V TYPICAL PERFORMANCE CHARACTERISTICS

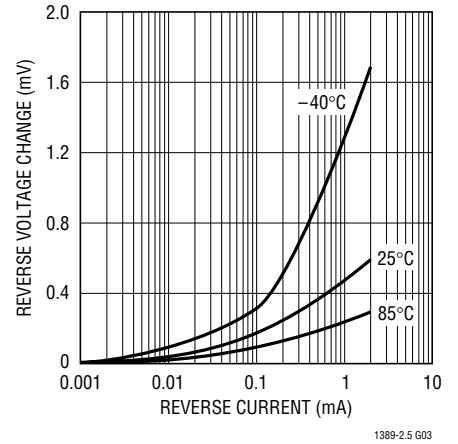
Reverse Characteristics



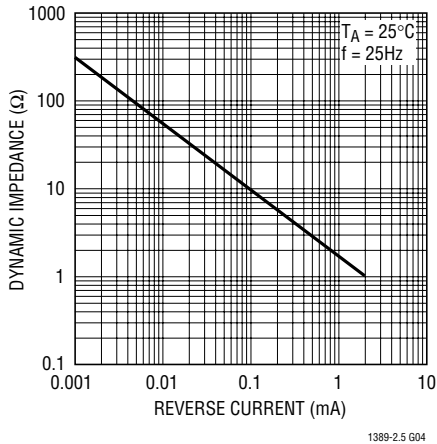
Temperature Drift



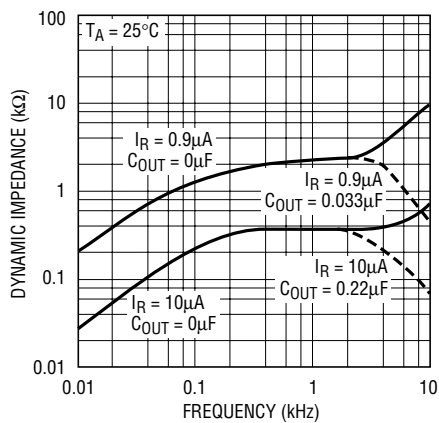
Reverse Voltage Change vs Current



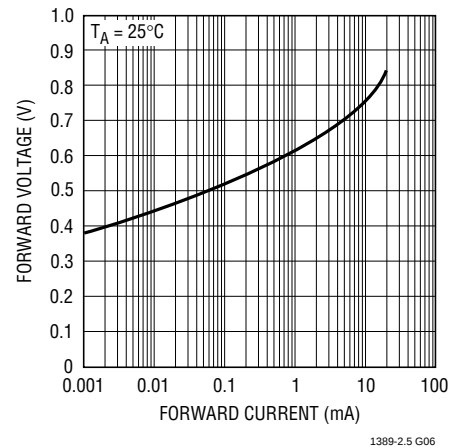
Reverse Dynamic Impedance



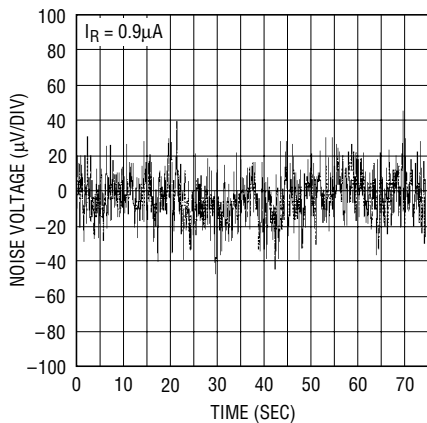
Dynamic Impedance vs Frequency



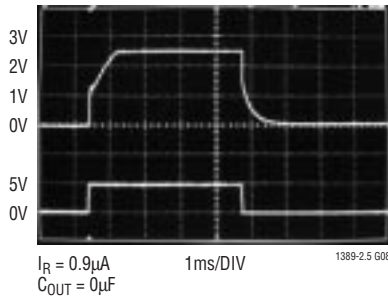
Forward Characteristics



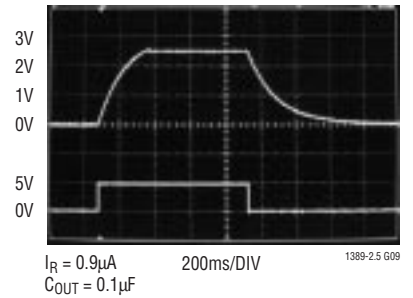
0.1Hz to 10Hz Noise



Response Time

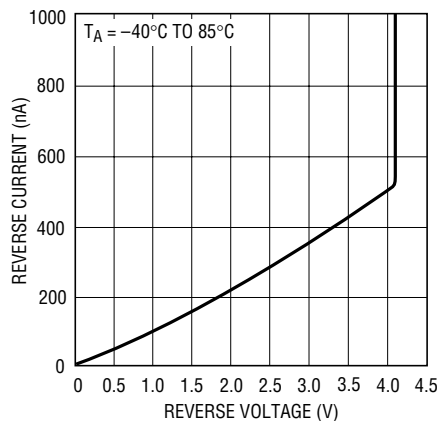


Response Time



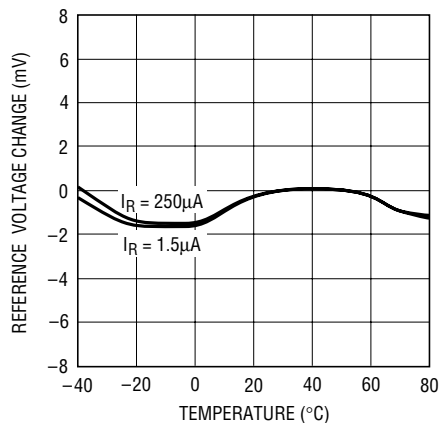
4.096V TYPICAL PERFORMANCE CHARACTERISTICS

Reverse Characteristics



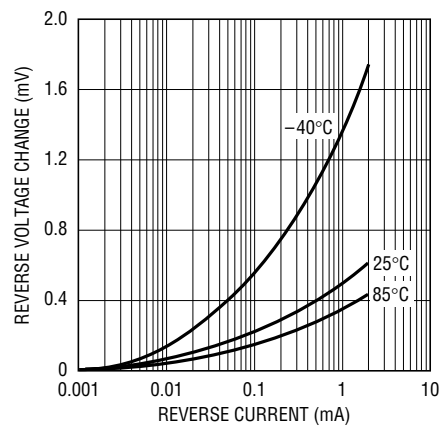
1389-4 G01

Temperature Drift



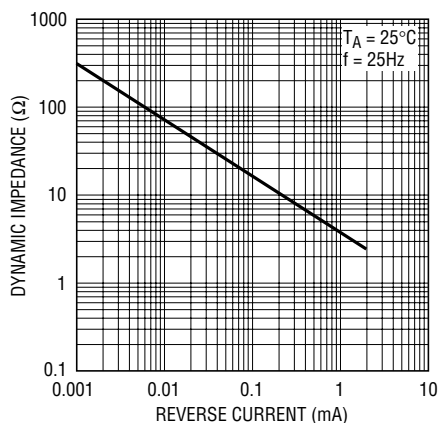
1389-4 G02

Reverse Voltage Change vs Current



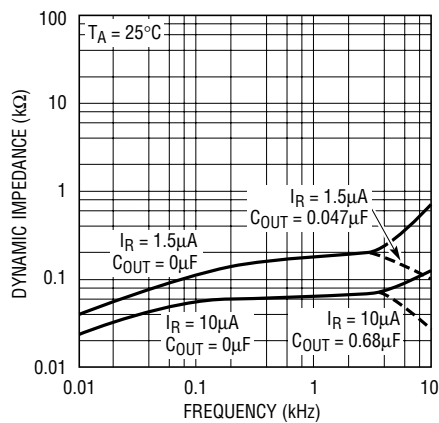
1389-4 G03

Reverse Dynamic Impedance



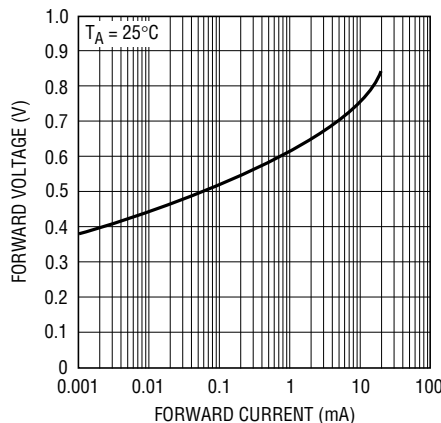
1389-4 G04

Dynamic Impedance vs Frequency



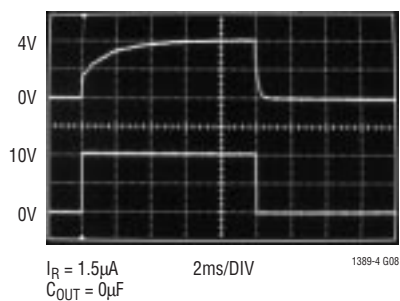
1389-4 G05

Forward Characteristics



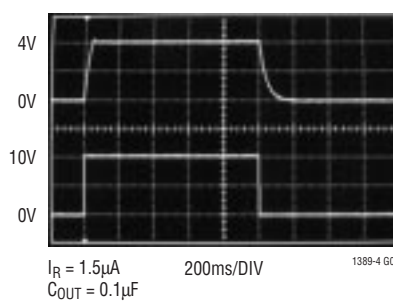
1389-4 G06

Response Time



1389-4 G08

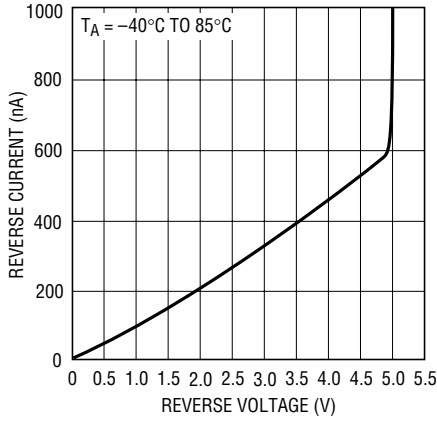
Response Time



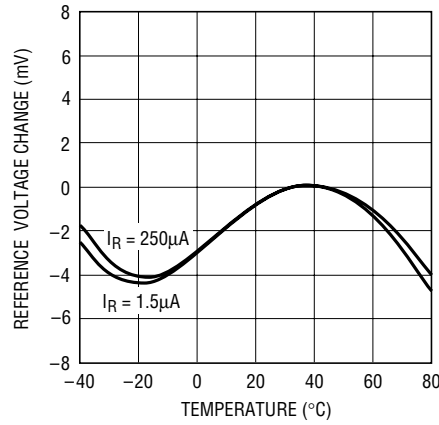
1389-4 G09

5V TYPICAL PERFORMANCE CHARACTERISTICS

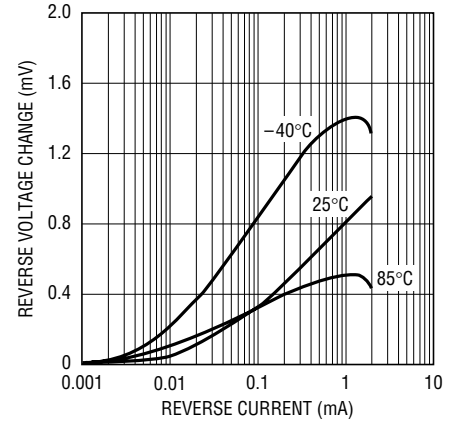
Reverse Characteristics



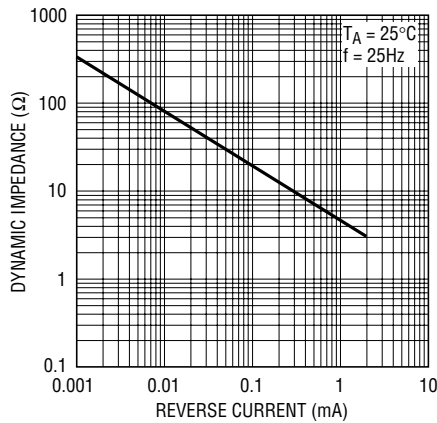
Temperature Drift



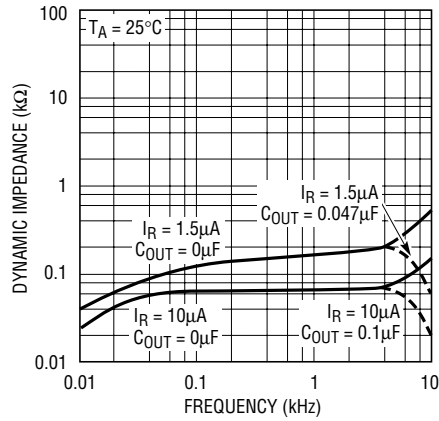
Reverse Voltage Change vs Current



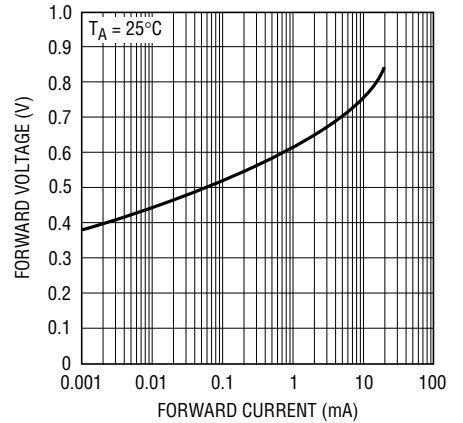
Reverse Dynamic Impedance



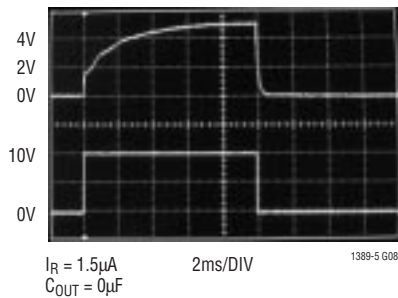
Dynamic Impedance vs Frequency



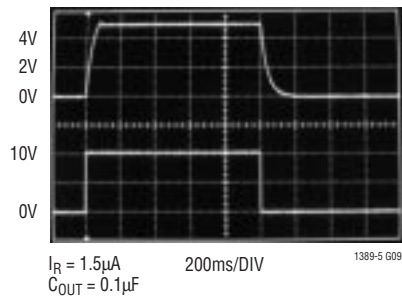
Forward Characteristics



Response Time



Response Time



APPLICATIONS INFORMATION

The reverse characteristics of the LT1389 resembles a simple resistor Zener diode parallel connection. This well behaved characteristic is important to the proper operation of circuits like Figure 1. The adjustable output voltage reference depends upon positive feedback from the LT1495's output to start-up and regulate the bias current for the LT1389. The LT1389 has no negative resistance regions that can interfere with the proper start-up of the buffered reference.

Board leakage is a concern for a nanopower precision shunt voltage reference. The LT1389 requires attention to detail in board layout in order to maximize its performance. $1.5\text{G}\Omega$ of leakage between a DNC pin and a 5V supply will conduct 2.5nA which induces a 0.2% error in V_{OUT} . Board leakage can be minimized by encircling the DNC pins with a guard ring operated at a potential of V_{OUT} . By tying the guard ring to V_{OUT} as shown in Figure 2, leakage paths are eliminated.

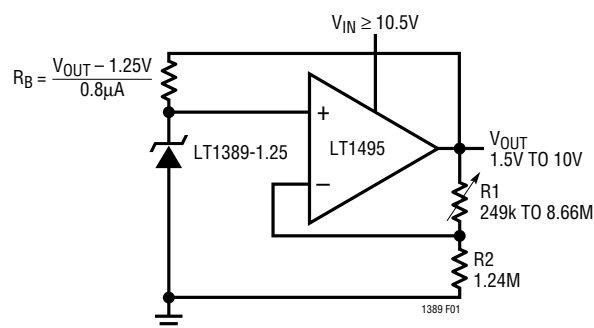


Figure 1. Adjustable Output Voltage Reference

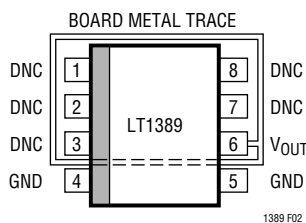


Figure 2. Guard Ring to Reduce Board Leakage

*WET SLUG TANTALUM

The circuit diagram shows a precision current source. It is powered by two 3 AAA Alkaline Cells connected in series. The circuit consists of two operational amplifiers, each labeled '1/2 LT1495', and a diode labeled 'LT1389-1.25'. Resistor R3 (249k, 0.1%) is connected between the positive supply and the non-inverting input of the first op-amp. The inverting input of the first op-amp is connected to the emitter of an NPN transistor labeled 'ZTX214C'. The collector of the transistor is connected to the non-inverting input of the second op-amp. Resistor R4 (300k, 5%) is connected between the positive supply and the non-inverting input of the second op-amp. The inverting input of the second op-amp is connected to the cathode of the diode. The anode of the diode is connected to the positive supply. The output of the second op-amp is connected to the positive supply through resistor R1 (200k, 0.1%) and to ground through resistor R2 (1M, 0.1%). The output current I_{OUT} is indicated as 1 μ A. The output voltage V_{OUT} is indicated as 1.5V. The diode is also labeled 'COM'.

2 AAA
ALKALINE
CELLS

R3 249k
0.1%

ZTX214C

1/2 LT1495

LT1389-1.25

R4 300k
5%

1/2 LT1495

R1 200k
0.1%

R2 1M
0.1%

$I_{OUT} = 1\mu A$

COM

$V_{OUT} = 1.5V$

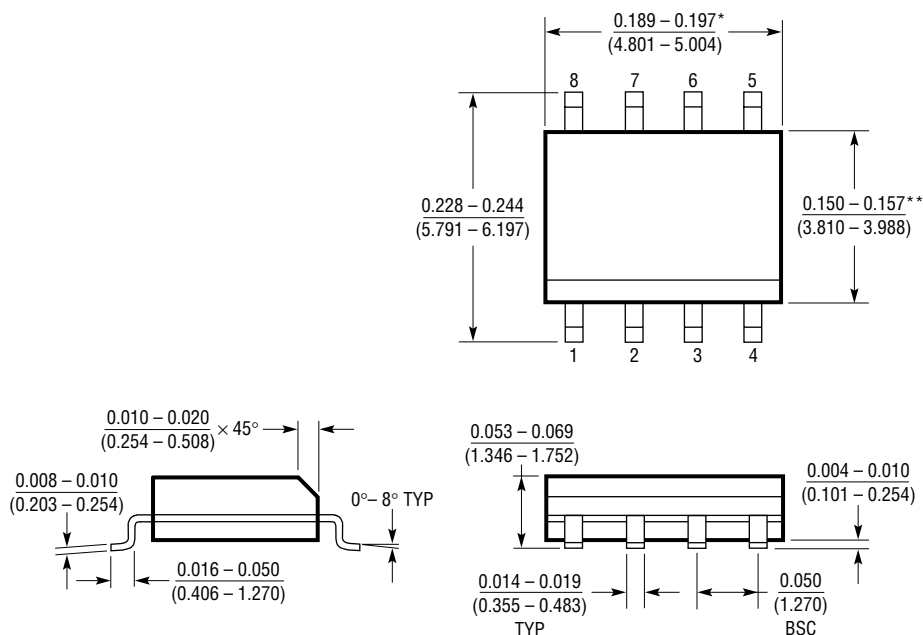
R1 TO R3: MAR5 SERIES, IRC (512) 992-7900

1389 TA02

PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

S8 Package
8-Lead Plastic Small Outline (Narrow 0.150)
 (LTC DWG # 05-08-1610)

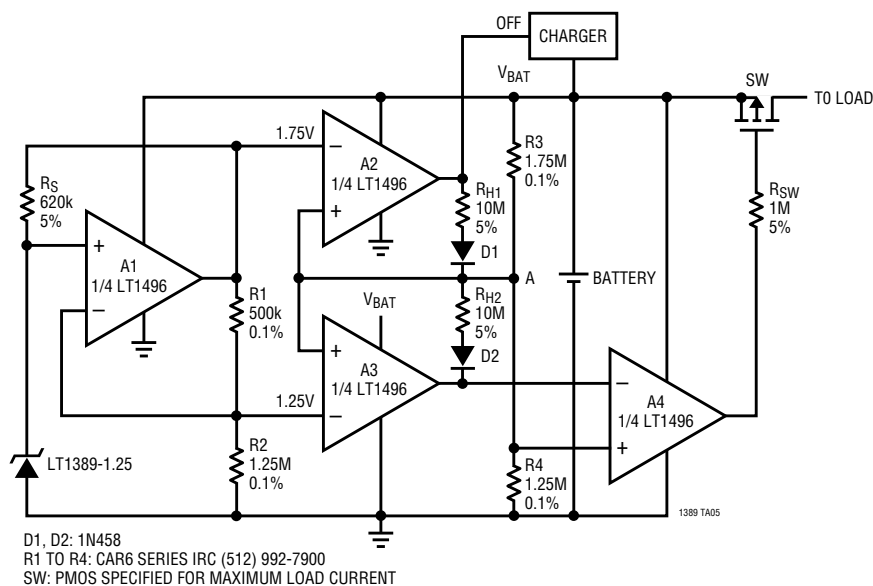


*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

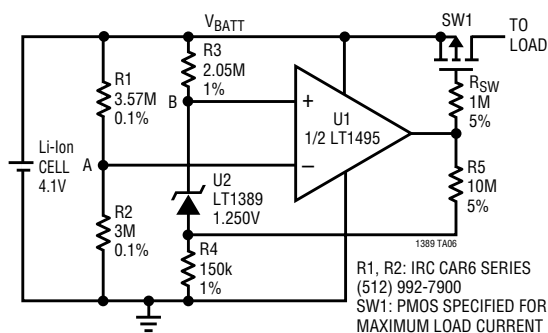
**DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

S08 1298

TYPICAL APPLICATIONS

Single Cell Li-Ion Battery Supervisory Circuit, $I_Q = 10\mu A$ 

Precision Undervoltage Lockout Circuit



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC®1440	Micropower Comparator with Reference	3.7 μA Max Supply Current, 1% 1.182V Reference, MSOP, PDIP and SO-8 Packages
LT1460	Micropower Series Reference	0.075% Max, 10ppm/°C Max Drift, 2.5V, 5V and 10V Versions, MSOP, PDIP, SO-8, SOT-23 and TO-92 Packages
LT1461	Micropower Precision LDO Series Reference	3ppm/°C Max Drift, 0°C to 70°C, -40°C to 85°C, -40°C to 125°C Options in SO-8
LT1495	1.5 μA Precision Rail-to-Rail Dual Op Amp	1.5 μA Max Supply Current, 100pA Max I_{OS}
LTC1540	Nanopower Comparator with Reference	600nA Max Supply Current, 2% 1.182V Reference, MSOP and SO-8 Packages
LT1634	Micropower Precision Shunt Voltage Reference	0.05% Max, 10ppm/°C Max Drift, 1.25V, 2.5V, 4.096V, 5V, 10 μA Maximum Supply Current
LTC1798	6 μA Low Dropout Series Reference	Available in Adjustable, 2.5V, 3V, 4.096V and 5V